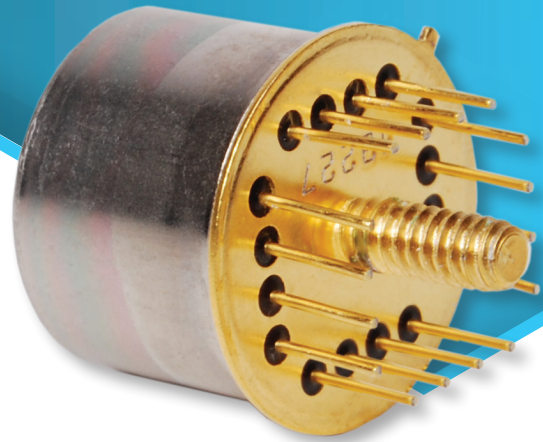




X-RAY APPLICATIONS

SXD30M-150-500-TO8

Silicon Drift Detector (SDD)



FEATURES

Detector System Includes:

- Silicon Drift Detector (SDD)
- Be Window (12.5 μm)
- Low noise JFET
- Peltier Cooler

PERFORMANCE

- Active Area: 45 mm²
- Collimated Active Area: 30 mm²
- Thickness: 0.5 mm
- Resolution <145 eV (FWHM)*
- Energy Range: 1 to 30 keV
- $\Delta T > 75\text{K}$ at 30 °C heat sink temperature

DESCRIPTION

The Mirion SDD using the proprietary PIPS® technology is a spectroscopy sub-system sensitive to X rays and low-energy gamma rays. It comprises a hermetically sealed silicon drift detector (SDD) element with a low noise FET assembly and a Peltier cooler. This product range is targeted to be integrated in handheld and bench top XRF systems. Mirion develops designs, manufactures and assembles everything in house, which has made us the partner of choice for a good number of industrial partners.

Model	Collimated Active Area (mm ²)	Collimator	PTB		Energy Resolution FWHM (eV)*	
					Typical	Max
SXD30M-150-500-TO8	30	Multilayer	Typical	Max	@ Optimum Rise Time	
			15000	>12000	135	145

*Energy resolution is given at 5.9 keV (Mn-Ka), with an ambient temperature ranging from +10 °C to +30 °C, on a digital spectroscopy system with trapezoid shaping filter. Cooled to -35 °C.

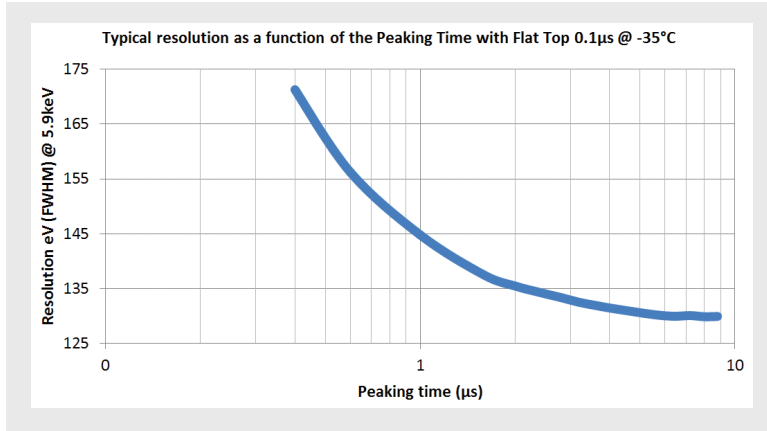


Figure 1: Typical resolution as a function of rise time at -35 °C.

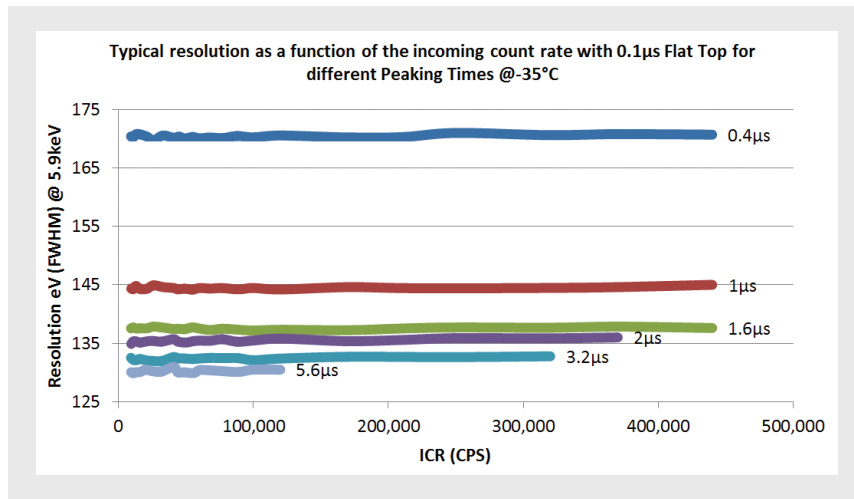


Figure 2: Typical resolution as a function of the incoming count rate at -35 °C.

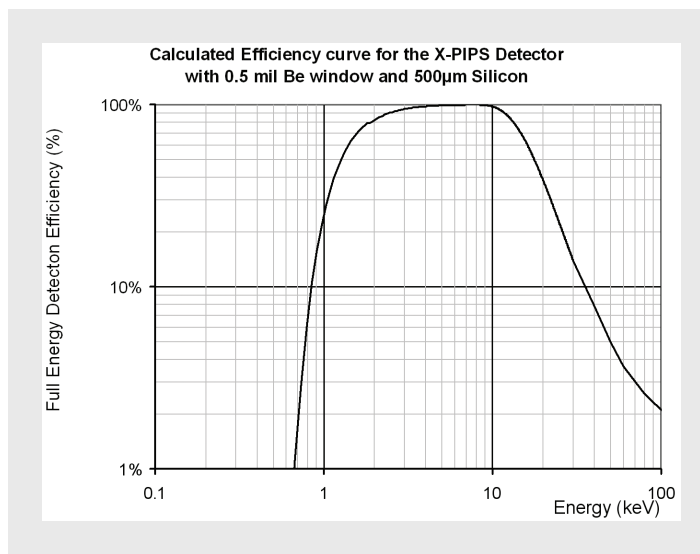


Figure 3: Calculated efficiency curve.

